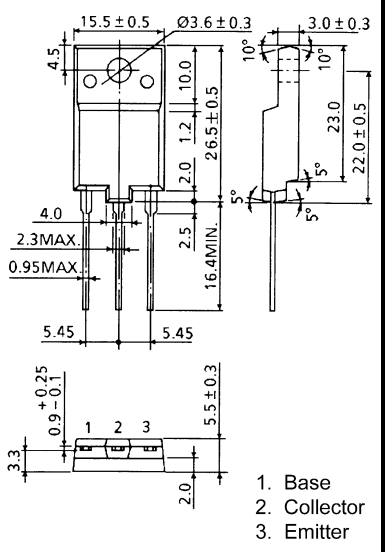
TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

2SD2550

HORIZONTAL DEFLECTION OUTPUT FOR COLOR TV

- High Voltage : V_{CBO} = 1700 V
- Low Saturation Voltage : $V_{CE\ (sat)}$ = 5.0 V (Max.)
- High Speed : t_f = 0.6 μs (Max.)
- Bult-in Damper Type
- Collector Metal (Fin) is Fully Covered with Mold Resin.

Unit: mm



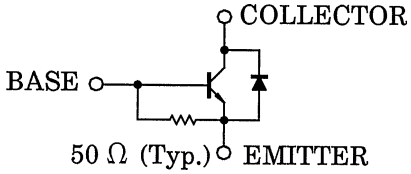
JEDEC	—
JEITA	—
TOSHIBA	2-16E3A

Weight: 5.5 g (typ.)

MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	1700	V
Collector-Emitter Voltage		V_{CEO}	600	V
Emitter-Base Voltage		V_{EBO}	5	V
Collector Current	DC	I_C	4	A
	Pulse	I_{CP}	8	
Base Current		I_B	2	A
Collector Power Dissipation		P_C	50	W
Junction Temperature		T_j	150	°C
Storage Temperature Range		T_{stg}	−55~150	°C

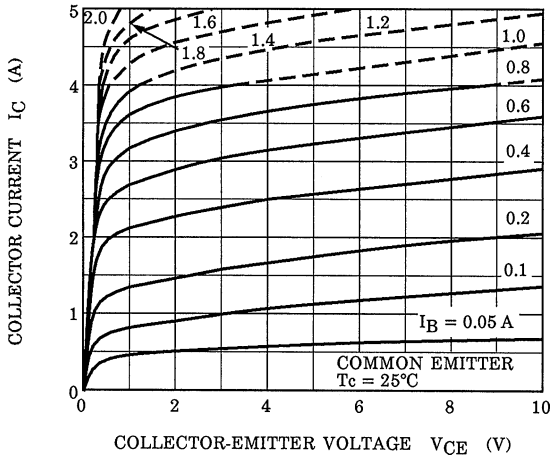
EQUIVALENT CIRCUIT



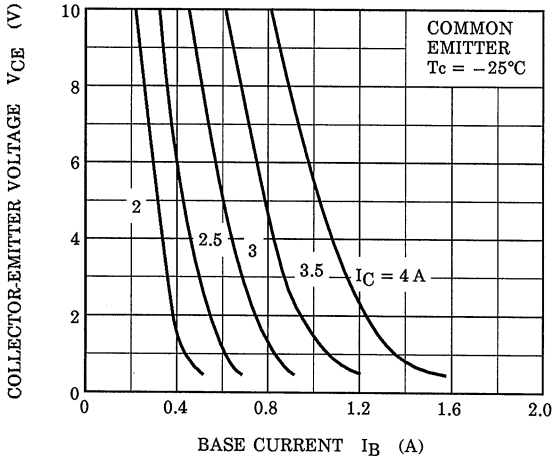
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Collector Cut−off Current		I_{CBO}	V_{CB} = 1700 V, I_E = 0	—	—	1	mA
Emitter Cut−off Current		I_{EBO}	V_{EB} = 5 V, I_C = 0	66	—	200	mA
Emitter−Base Breakdown Voltage		$V_{(BR)\ EBO}$	I_C = 400 mA, I_B = 0	5	—	—	V
DC Current Gain		h_{FE}	V_{CE} = 5 V, I_C = 1 A	8	—	22	—
Collector−Emitter Saturation Voltage		$V_{CE\ (sat)}$	I_C = 3 A, I_B = 0.8 A	—	5	8	V
Base−Emitter Saturation Voltage		$V_{BE\ (sat)}$	I_C = 3 A, I_B = 0.8 A	—	—	1.2	V
Forward Voltage (Damper Diode)		V_F	I_F = 4 A	—	1.5	2.0	V
Transition Frequency		f_T	V_{CE} = 10 V, I_C = 0.1 A	—	3	—	MHz
Collector Output Capacitance		C_{ob}	V_{CB} = 10 V, I_E = 0, f = 1 MHz	—	85	—	pF
Switching Time	Storage Time	t_{stg}	I_{CP} = 3 A, I_{B1} (end) = 0.8 A f_H = 15.75 kHz	—	7.5	10	μs
	Fall Time	t_f		—	0.3	0.6	

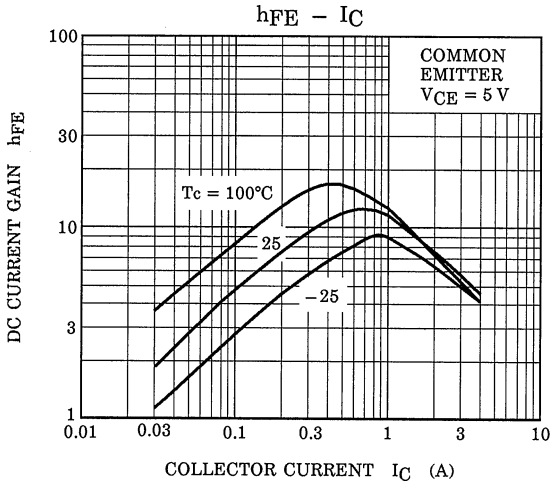
$I_C - V_{CE}$



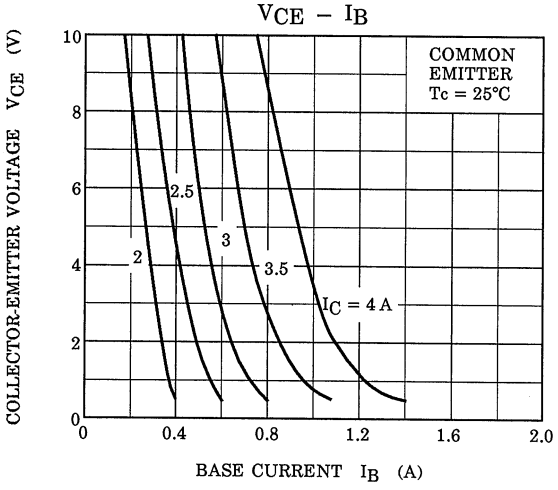
$V_{CE} - I_B$



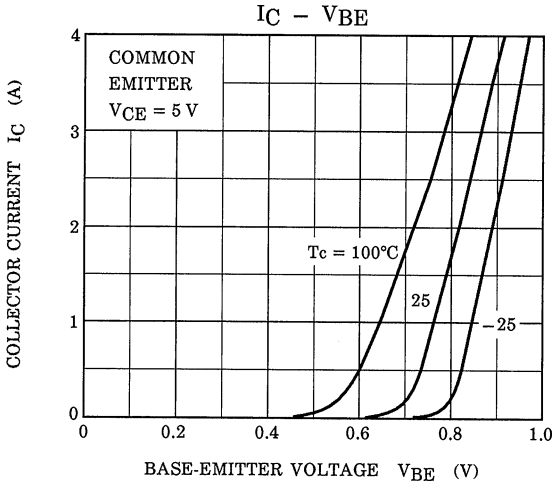
$h_{FE} - I_C$



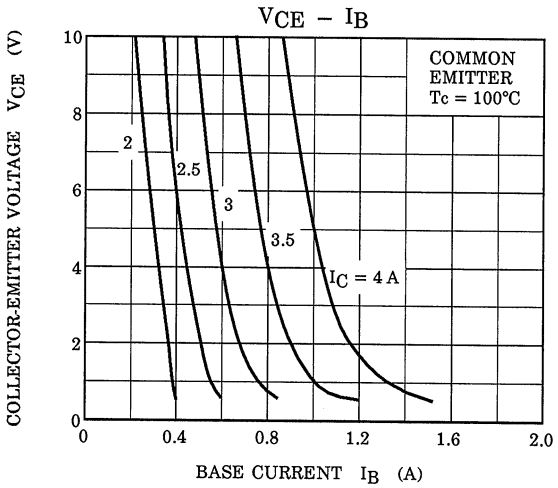
$V_{CE} - I_B$



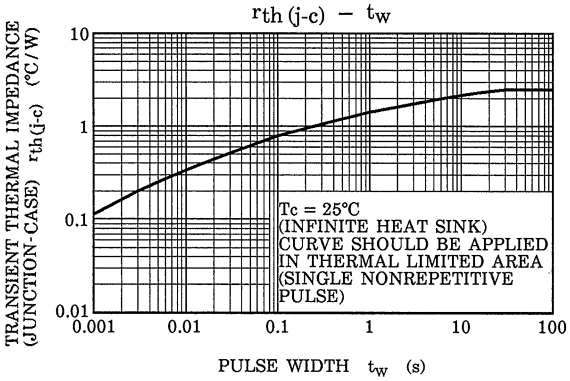
$I_C - V_{BE}$



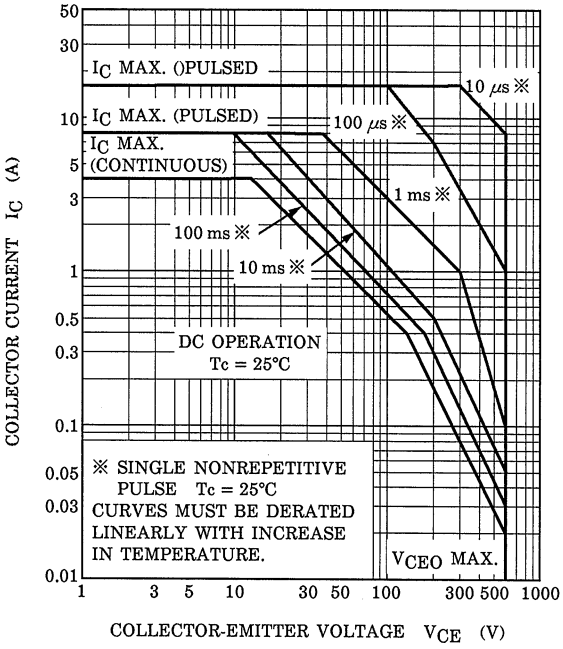
$V_{CE} - I_B$



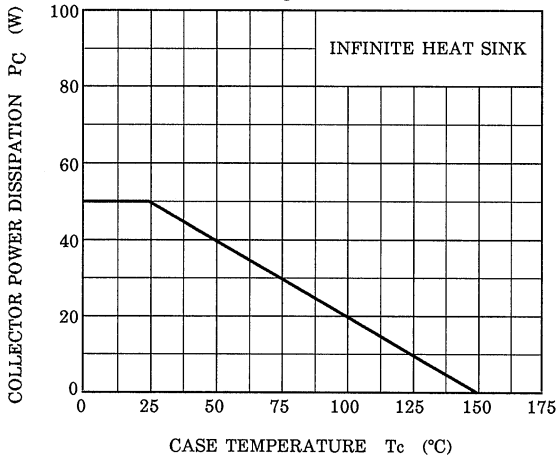
$r_{th\,(j\text{-}c)}$ – t_w



SAFE OPERATING AREA



P_C – Tc



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